



MMBTH10

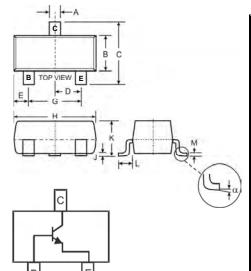
NPN SURFACE MOUNT VHF/UHF TRANSISTOR

Features

- Designed for VHF/UHF Amplifier Applications and High Output VHF Oscillators
- High Current Gain Bandwidth Product
- Ideal for Mixer and RF Amplifier Applications with collector currents in the 100µA - 30 mA Range
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 3 and 4)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: K3H, K3Y; See Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)



SOT-23									
Dim	Min	Max							
Α	0.37	0.51							
В	1.20	1.40							
C	2.30	2.50							
D	0.89	1.03							
E	0.45	0.60 2.05							
G	1.78								
Н	2.80	3.00							
J	0.013	0.10							
K	0.903	1.10							
L	0.45	0.61							
М	0.085	0.180							
α	0°	8°							
All Dimensions in mm									

Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	30	V
Collector-Emitter Voltage	V _{CEO}	25	V
Emitter-Base Voltage	V _{EBO}	3.0	V
Collector Current - Continuous (Note 1)	I _C	50	mA
Power Dissipation (Note 1)	P _D	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ heta JA}$	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics @TA = 25°C unless otherwise specified

	0			11-16	Total Compilition					
Characteristic	Symbol	Min	Max	Unit	Test Condition					
OFF CHARACTERISTICS (Note 2)										
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	25	_	V	$I_C = 1 \text{mA}, I_B = 0$					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	30	_	V	$I_C = 100 \mu A, I_E = 0$					
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	3.0	_	V	$I_E = 10\mu A, I_C = 0$					
Collector Cutoff Current	I _{CBO}	_	100	nA	$V_{CB} = 25V, I_E = 0$					
Emitter Cutoff Current	I _{EBO}	_	100	nA	$V_{EB} = 2V, I_{C} = 0$					
ON CHARACTERISTICS (Note 2)										
DC Current Gain	h _{FE}	60	_	_	$I_C = 4mA, V_{CE} = 10.0V$					
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.5	V	$I_C = 4mA$, $I_B = 400\mu A$					
Base-Emitter On Voltage	V _{BE(SAT)}	_	0.95	V	$I_C = 4mA, V_{CE} = 10.0V$					
SMALL SIGNAL CHARACTERISTICS										
Current Gain-Bandwidth Product	f _T	650	_	MHz	$V_{CE} = 10V$, $f = 100MHz$, $I_{C} = 4mA$					
Collector-Base Capacitance	C _{CB}	_	0.7	pF	$V_{CB} = 10V$, $f = 1.0MHz$, $I_E = 0$					
Collector-Base Feedback Capacitance	C _{RB}	_	0.65	pF	V _{CB} = 10V, f = 1.0MHz, I _E = 0					
Collector-Base Time Constant	Rb'Cc	_	9	ps	$V_{CB} = 10V$, $f = 31.8MHz$, $I_{C} = 4mA$					

Notes:

- Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch, pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- Short duration pulse test used to minimize self-heating effect.
- No purposefully added lead. Halogen and Antimony Free.
- Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.



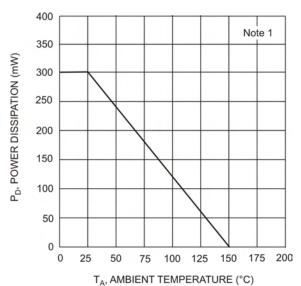
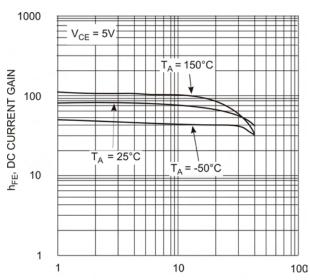
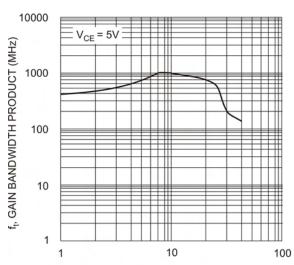


Fig. 1, Max Power Dissipation vs Ambient Temperature



 I_C , COLLECTOR CURRENT (mA) Fig. 3, DC Current Gain vs. Collector Current



I_C, COLLECTOR CURRENT (mA) Fig. 5, Gain Bandwidth Product vs Collector Current

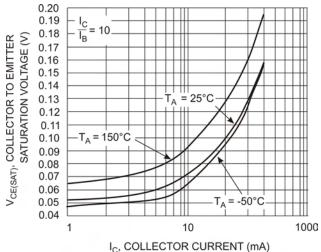


Fig. 2 Collector Emitter Saturation Voltage vs. Collector Current

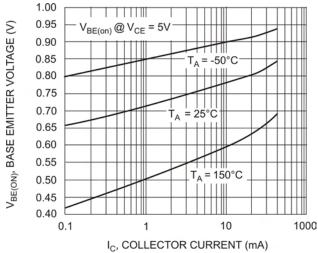


Fig. 4 Base Emitter Voltage vs. Collector Current

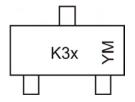


Ordering Information (Note 5)

Device	Packaging	Shipping			
MMBTH10-7-F	SOT-23	3000/Tape & Reel			

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K3x = Product Type Marking Code, e.g. K3H YM = Date Code Marking

Y = Year ex: N = 2002M = Month ex: 9 = September

Date Code Key

Date Code N	Су														
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	М	N	Р	R	S	Т	U	V	W	Χ	Υ	Z
Month	Jan	Fe	b I	Mar	Apr	May	Ju	n	Jul	Aug	Sep	Oc	t N	Nov	Dec
Code	1	2		3	4	5	6		7	8	9	0		N	D

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